

### SPICE Device Model Si4462DY

### **Vishay Siliconix**

### N-Channel 200-V (D-S) MOSFET

#### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

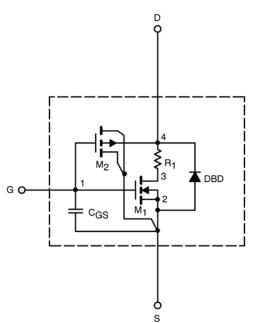
- Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

#### DESCRIPTION

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to  $125^{\circ}$ C temperature ranges under the pulsed 0-V to 10-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

#### SUBCIRCUIT MODEL SCHEMATIC

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.



SPECIFICATIONS (T <sub>J</sub> = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}$ = $V_{GS}$ , $I_D$ = 250 $\mu$ A	2.6		V
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{\text{DS}}~\geq 5$ V, $V_{\text{GS}}$ = 10 V	13		А
Drain-Source On-State Resistance <sup>a</sup>	r <sub>DS(on)</sub>	$V_{GS}$ = 10 V, I <sub>D</sub> = 1.5 A	0.37	0.39	Ω
		$V_{GS}$ = 6 V, I <sub>D</sub> = 1.45 A	0.40	0.42	
Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_{\rm S}$ = 2.1 A, $V_{\rm GS}$ = 0 V	0.81	0.80	V
Dynamic <sup>b</sup>					
Total Gate Charge	Qg	$V_{DS}$ = 100 V, $V_{GS}$ = 10 V, $I_{D}$ = 1.5 A	5.7	6	nC
Gate-Source Charge	Q <sub>gs</sub>		0.90	0.90	
Gate-Drain Charge	Q <sub>gd</sub>		1.9	1.9	
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{DD} = 100 \text{ V}, \text{ R}_{L} = 100 \Omega$ $\text{I}_{D} \cong 1 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{G}} = 6 \Omega$ $\text{I}_{\text{F}} = 2.1 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$	10	10	ns
Rise Time	tr		12	12	
Turn-Off Delay Time	t <sub>d(off)</sub>		10	10	
Fall Time	t <sub>f</sub>		6	15	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>		60	55	

Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2%. b. Guaranteed by design, not subject to production testing.



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T<sub>C</sub> = 125°C

25°C

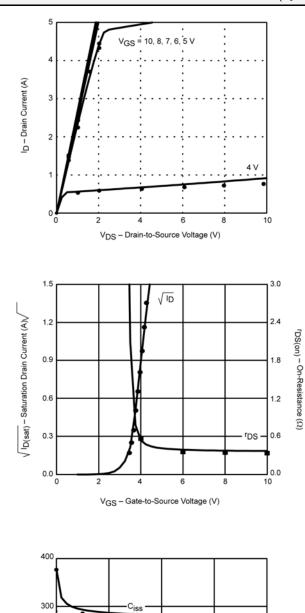
COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

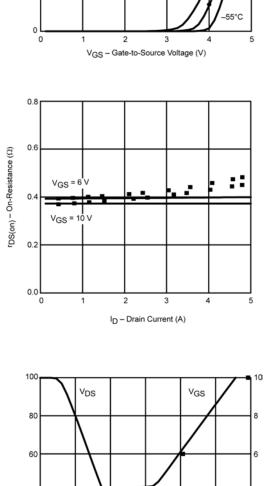
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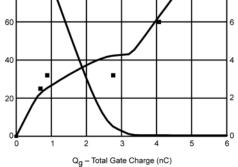
60

80

ID – Drain Current (A)







Note: Dots and squares represent measured data.

Coss

40

V<sub>DS</sub> – Drain-to-Source Voltage (V)

20

C – Capacitance (pF)

200

100

0

0



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## Disclaimer

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